

## Supporting information

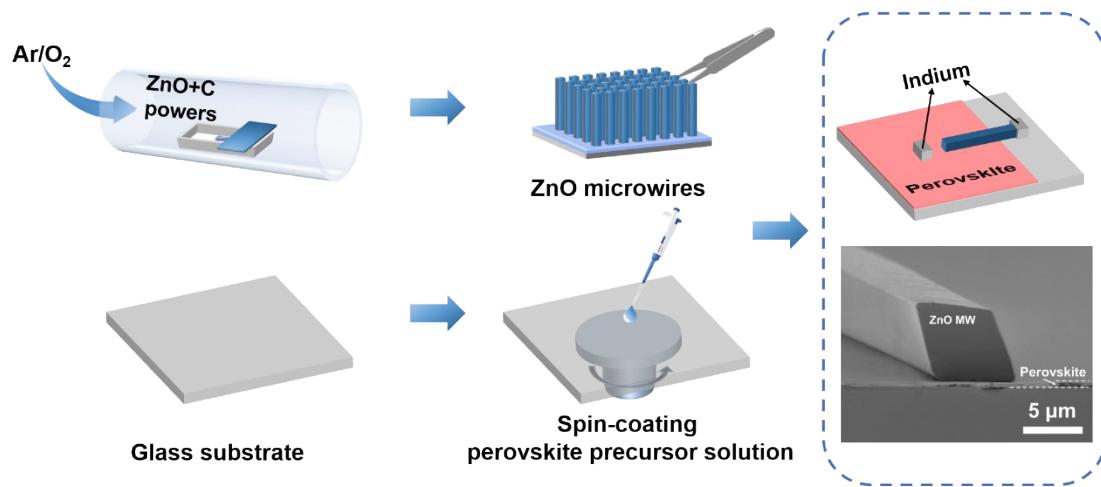
### Reconfigurable self-powered imaging photodetectors by reassembling and disassembling ZnO/perovskite heterojunction

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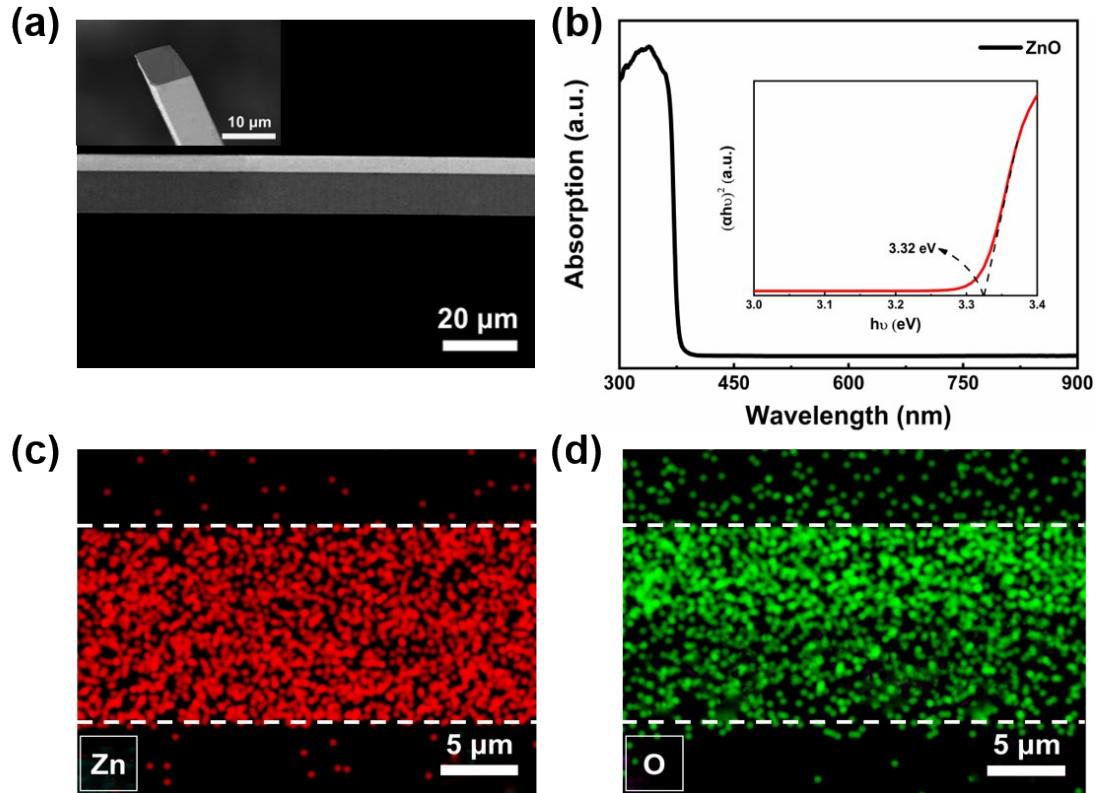
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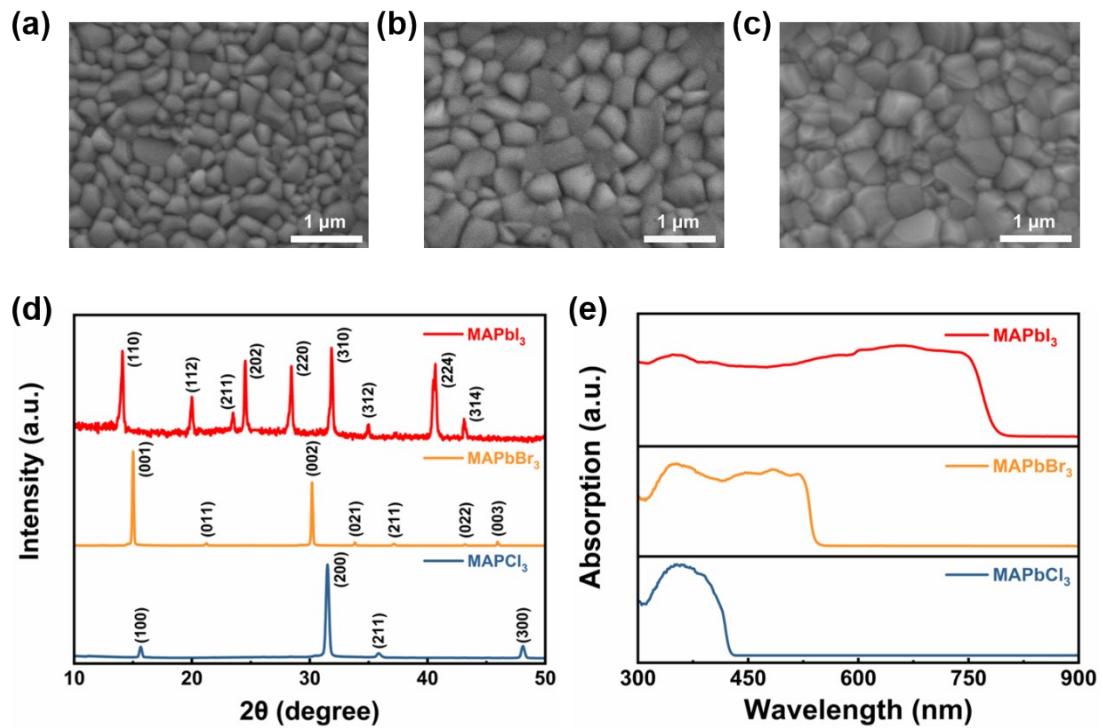
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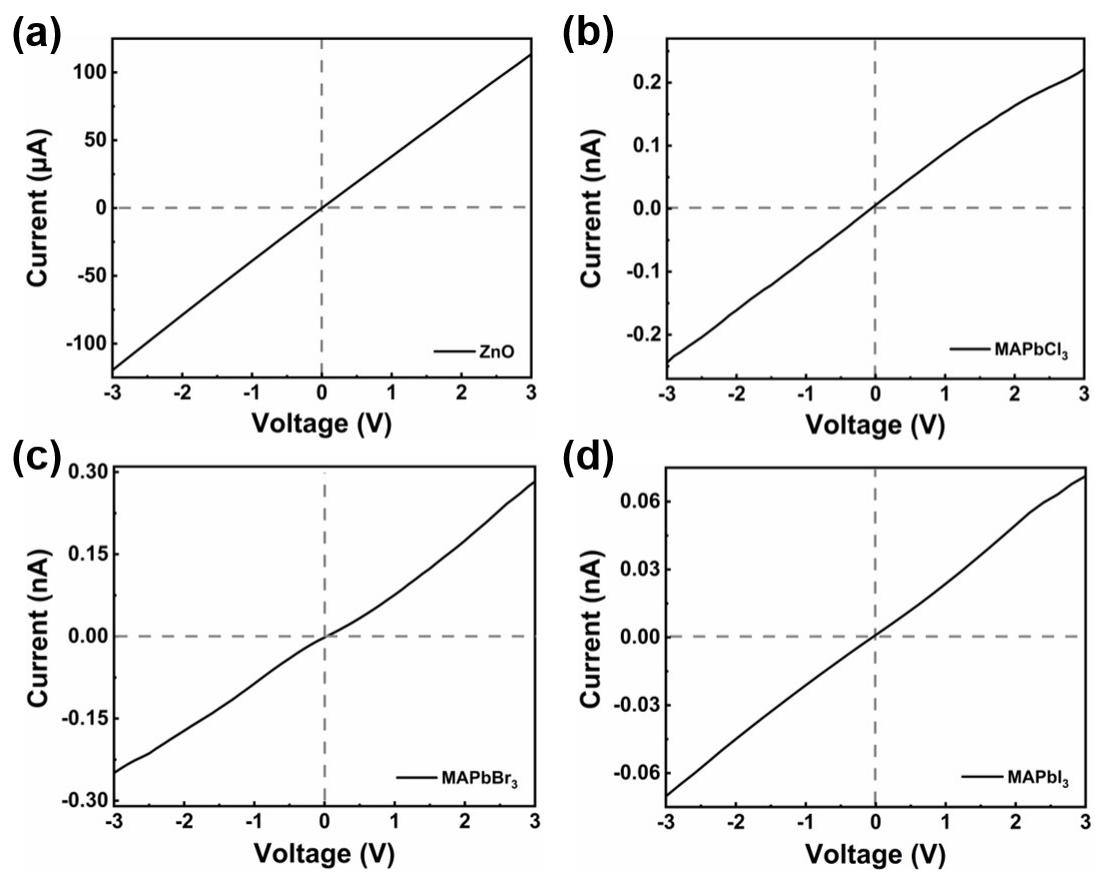
**Fig. S1** Schematic illustration of the ZnO MW/Perovskite heterojunction fabrication process.



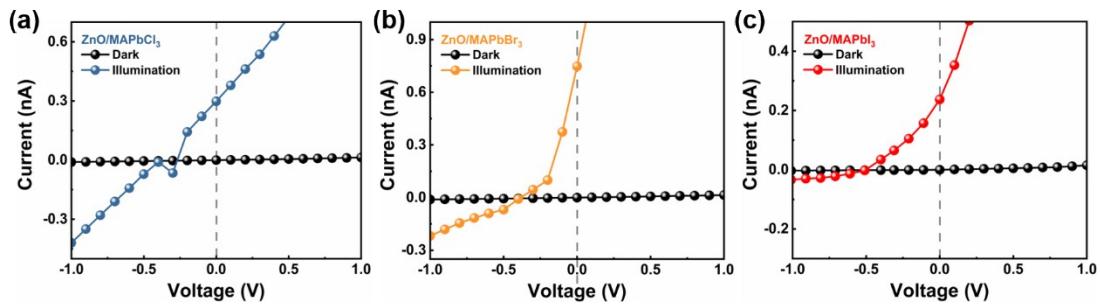
**Fig. S2** (a) The SEM images of the ZnO MW, with the cross-section shown in the inset. (b) The optical absorption spectrum of the ZnO MW. The corresponding elemental mapping distributions of (c) Zn and (d) O in ZnO MW.



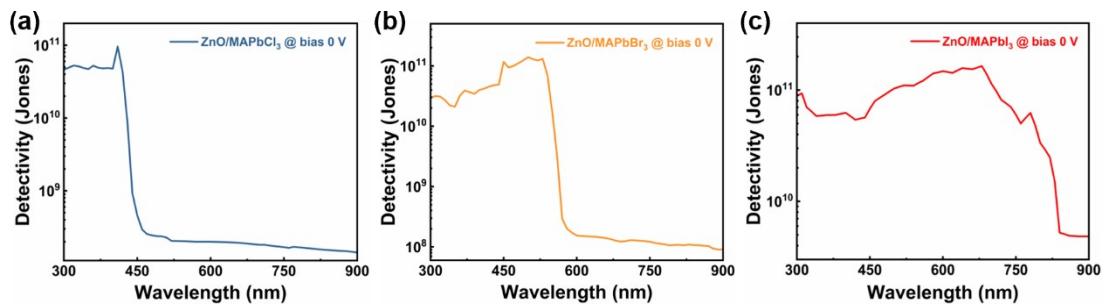
**Fig. S3** (a-c) The SEM images of  $\text{MAPbCl}_3$ ,  $\text{MAPbBr}_3$  and  $\text{MAPbI}_3$  film. (d) The XRD and (e) The absorption spectra of  $\text{MAPbI}_3$ ,  $\text{MAPbBr}_3$  and  $\text{MAPbCl}_3$  film, respectively.



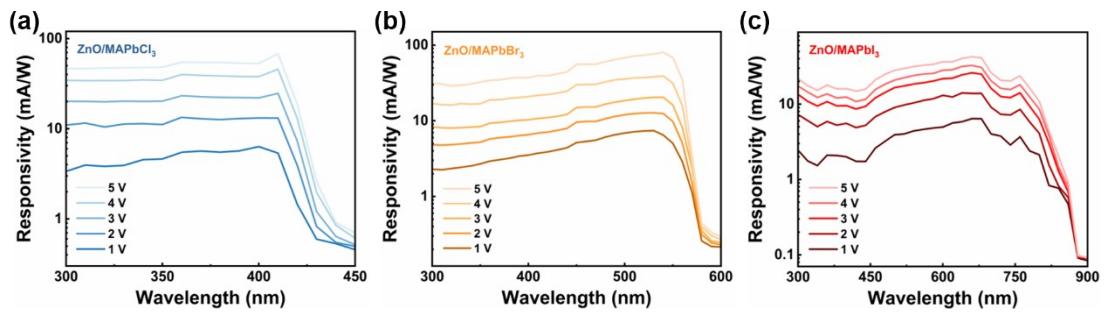
**Fig. S4** The  $I$ - $V$  curves of (a) Indium-ZnO MW-Indium, (b) Indium-MAPbCl<sub>3</sub>-Indium, (c) Indium-MAPbBr<sub>3</sub>-Indium and (d) Indium-MAPbI<sub>3</sub>-Indium under dark.



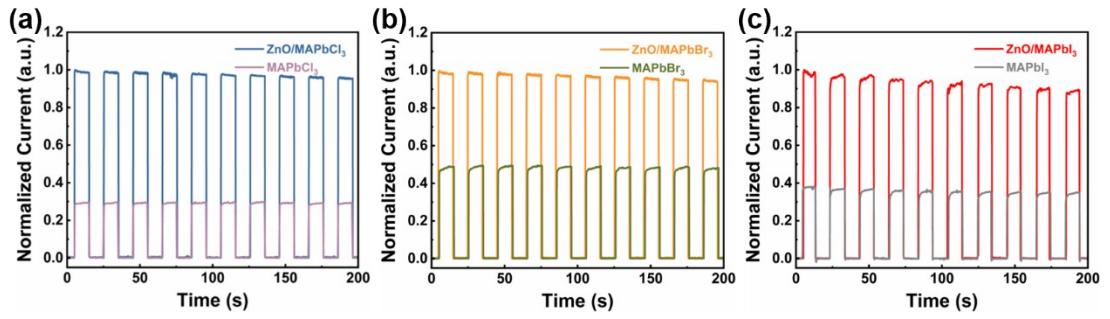
**Fig. S5** The linear  $I$ - $V$  curves of (a) ZnO MW/MAPbCl<sub>3</sub>, (b) ZnO MW/MAPbBr<sub>3</sub> and (c) ZnO MW/MAPbI<sub>3</sub> in dark and under illumination (AM 1.5G, 100 mW cm<sup>-2</sup>) near the 0 V.



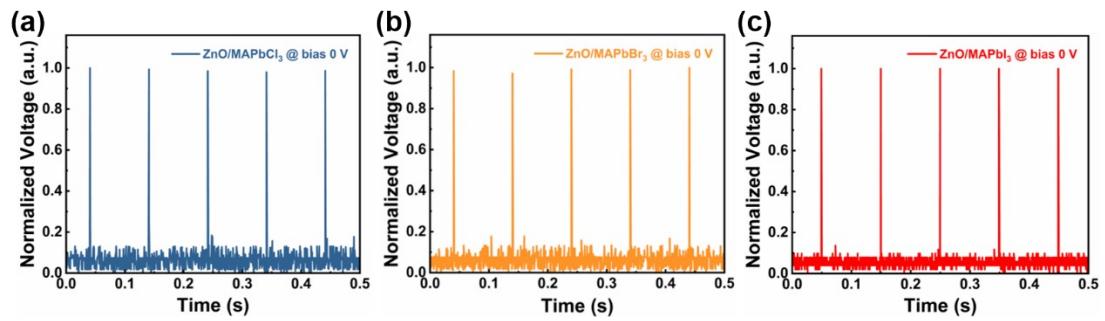
**Fig. S6** (a-c) The detectivity spectrum of the ZnO MW/MAPbCl<sub>3</sub>, ZnO MW/MAPbBr<sub>3</sub> and ZnO MW/MAPbI<sub>3</sub> heterojunction photodetector at 0 V.



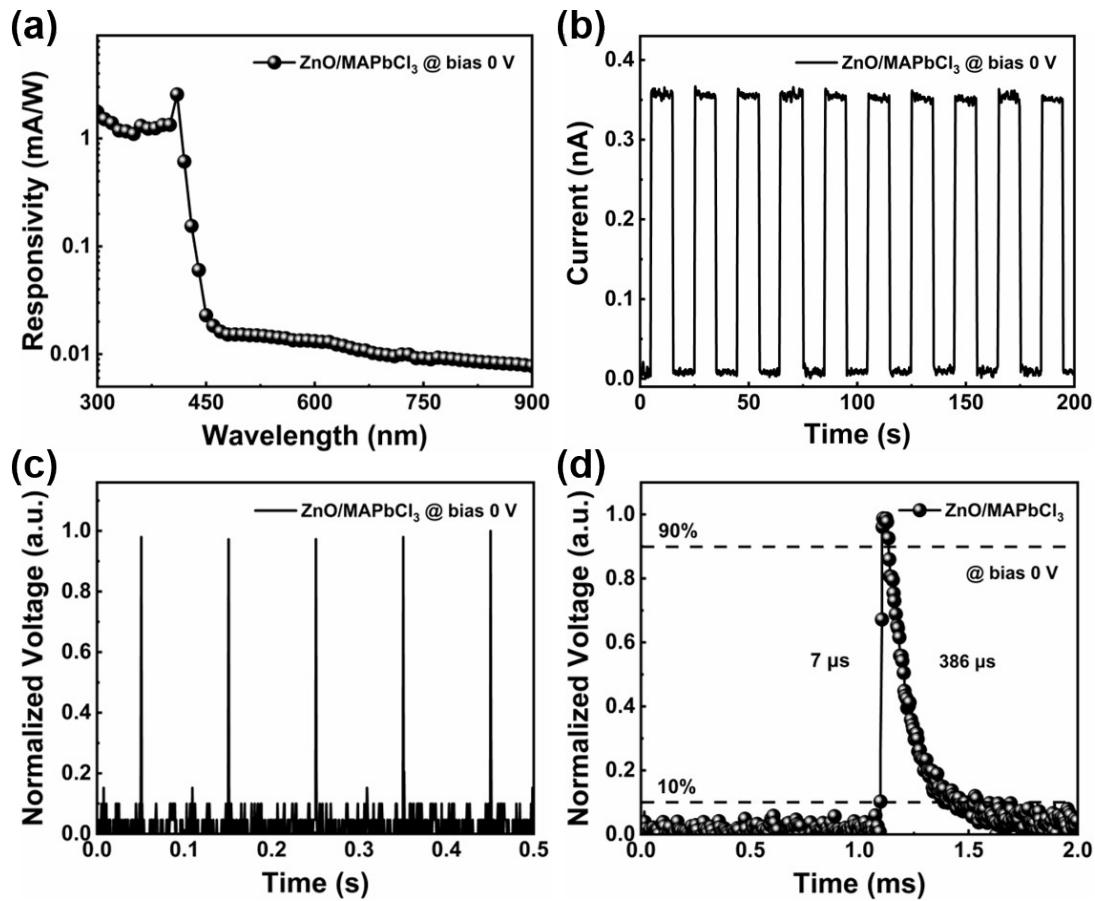
**Fig. S7** (a-c) The photoresponse spectra of the ZnO MW/MAPbCl<sub>3</sub>, ZnO MW/MAPbBr<sub>3</sub> and ZnO MW/MAPbI<sub>3</sub> heterojunction photodetector at different bias voltage.



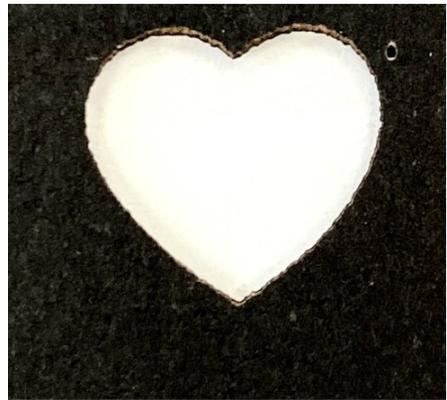
**Fig. S8** (a-c) Time-dependent response of heterojunction and perovskite film photodetectors at 5 V under illumination (AM 1.5G, 100 mW cm<sup>-2</sup>).



**Fig. S9** (a-c) Transient photoresponse of the ZnO MW/MAPbCl<sub>3</sub>, ZnO MW/MAPbBr<sub>3</sub> and ZnO MW/MAPbI<sub>3</sub> heterojunction photodetector at 0 V.



**Fig. S10** (a) The responsivity spectra of the second reassembly ZnO MW/MAPbCl<sub>3</sub> at 0 V. (b) Time-dependent response of ZnO MW/MAPbCl<sub>3</sub> photodetectors at 0 V under illumination (AM 1.5G, 100 mW cm<sup>-2</sup>). (c) Transient photoresponse and (d) a single period transient photoresponse of the ZnO MW/MAPbCl<sub>3</sub> at 0 V under the excitation of 355 nm pulsed laser.



**Fig. S11** The image for the object “heart” on black cardboard.